

TOSHIBA PHOTOCOUPLER GaAlAs IRED & PHOTO-DIODE ARRAY

TLP3914

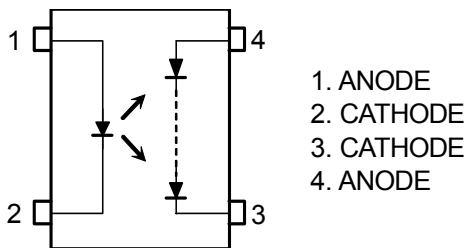
TELECOMMUNICATION
 PROGRAMMABLE CONTROLLERS
 MOS FET GATE DRIVER

The TOSHIBA SSOP coupler TLP3914 is a small outline coupler, suitable for surface mount assembly.
 The TLP3914 consists of a GaAlAs light emitting diode, optically coupled to a series connected photo diode array which is suitable for MOS FET gate drive.

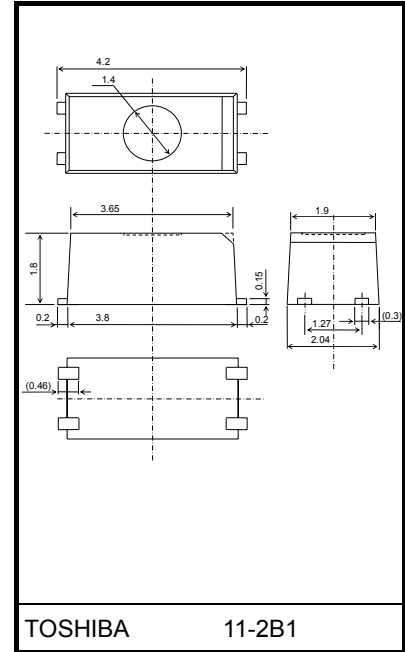
FEATURES

- 4 pin SSOP (SSOP4) : 1.8 mm high, 1.27 mm pitch
- Open Voltage : 7V (min)
- Short Current : 20 μ A (min)
- Isolation Voltage : 1500Vrms (min)

PIN CONFIGURATION (TOP VIEW)



Unit in mm



Weight: 0.03 g

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward Current	I_F	30	mA
	Forward Current Derating (Ta ≥ 25°C)	$\Delta I_F / ^\circ\text{C}$	-0.3	mA / °C
	Reverse Voltage	V_R	5	V
	Junction Temperature	T_j	125	°C
DETECTOR	Forward Current	I_{FD}	50	μA
	Reverse Voltage	V_{RD}	10	V
	Junction Temperature	T_j	125	°C
Storage Temperature Range		T_{stg}	-55~125	°C
Operating Temperature Range		T_{opr}	-40~85	°C
Lead Soldering Temperature (10 s)		T_{sol}	260	°C
Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note 1)		BV_S	1500	Vrms

(Note 1) : Device considered a two terminal device: Pins 1 and 2 shorted together and pins 3 and 4 shorted together.

CAUTION

This device is sensitive to electrostatic discharge. When using this device, please ensure that all tools and equipment are earthed.

RECOMMENDED OPERATING CONDITIONS (Note 2)

Characteristic	Symbol	Min	Typ.	Max	Unit
Forward Current	I_F	7	—	20	mA
Operating Temperature	T_{opr}	-25	—	65	°C

(Note 2) : Recommended operating conditions are given as a design guideline to obtain expected performance of the device.

Additionally, each item is an independent guideline respectively.

In developing designs using this product, please confirm specified characteristics shown in this document.

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward Voltage	V_F	$I_F = 10 \text{ mA}$	1.15	1.30	1.45	V
	Reverse Current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
DETECTOR	Forward Voltage	V_{FD}	$I_{FD} = 10 \text{ μA}$	—	9.6	—	V
	Reverse Current	I_{RD}	$V_{RD} = 10 \text{ V}$	—	1	—	nA
	Capacitance (Anode to Cathode)	C_{TD}	$V = 0, f = 1 \text{ MHz}$	—	2.5	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Open-Circuit Voltage	V _{OC}	I _F = 10 mA	7	—	—	V
Short-Circuit Current	I _{SC}	I _F = 10 mA	20	—	—	μA

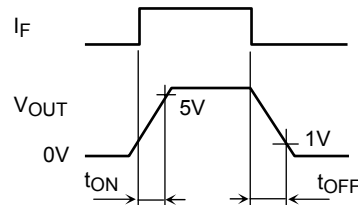
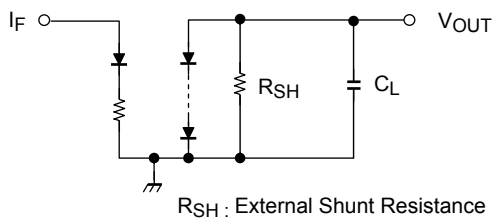
ISOLATION CHARACTERISTICS (Ta = 25°C)

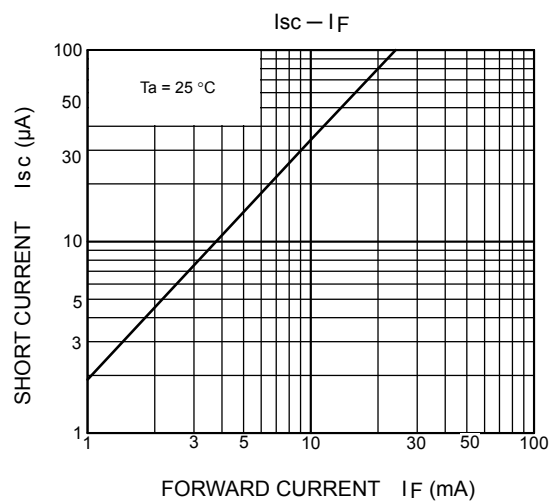
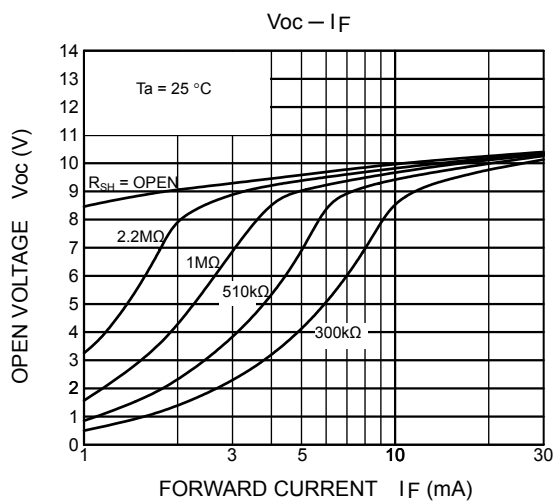
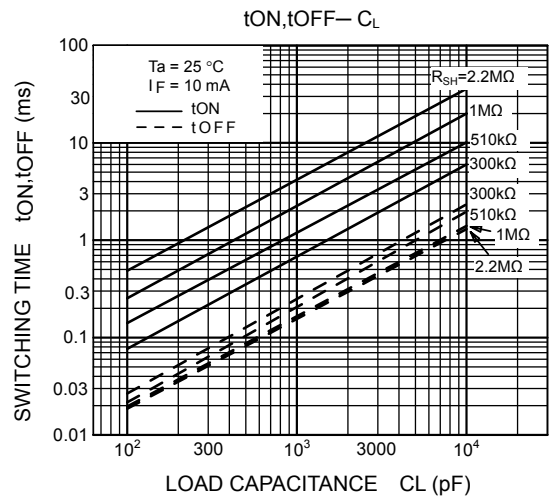
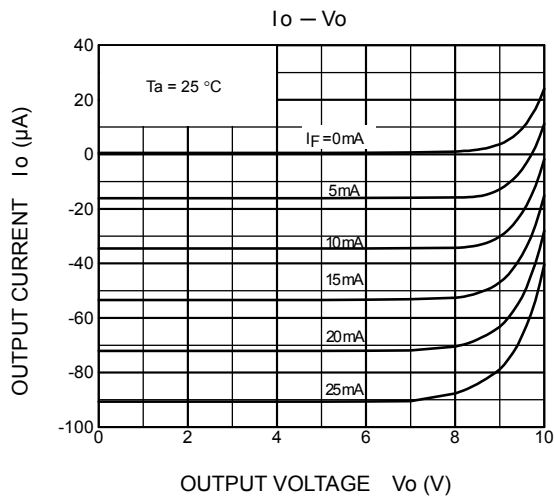
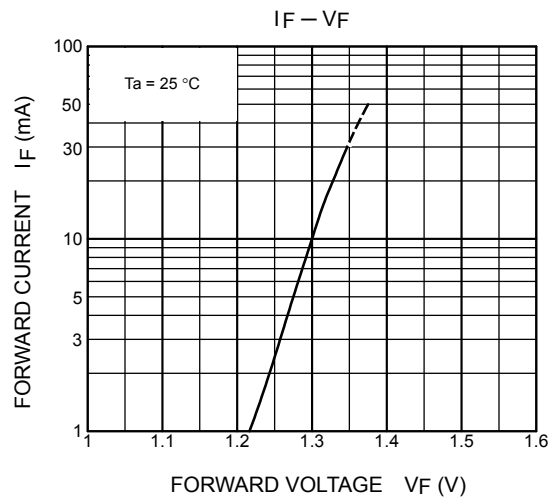
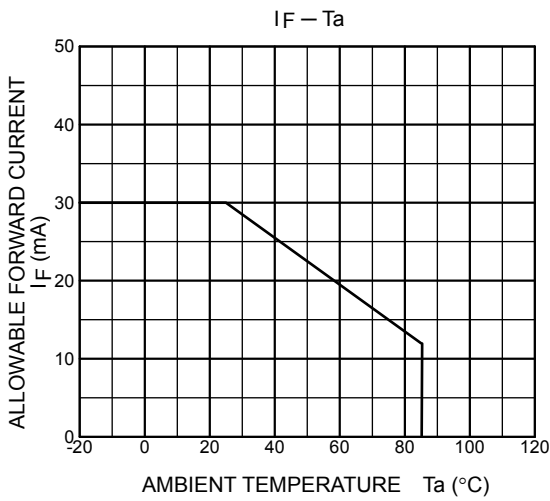
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance Input to Output	C _S	V _S = 0, f = 1 MHz	—	0.8	—	pF
Isolation Resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	—	Ω
Isolation Voltage	BV _S	AC, 1 minute	1500	—	—	V _{rms}
		AC, 1 second in oil	—	3000	—	
		DC, 1 minute in oil	—	3000	—	V _{dc}

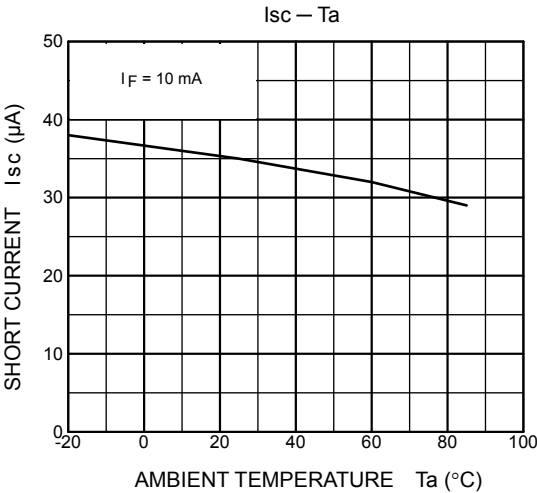
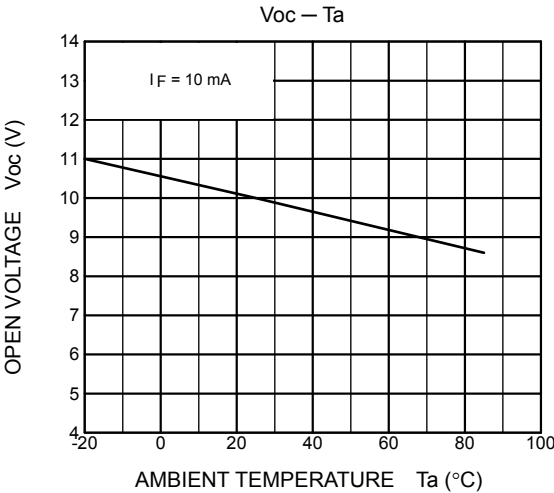
SWITCHING CHARACTERISTICS (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on Time	t _{ON}	I _F = 10 mA, R _{SH} = 300 kΩ	—	0.3	—	ms
Turn-off Time	t _{OFF}	C _L = 1000pF (Note 3)	—	0.6	—	ms

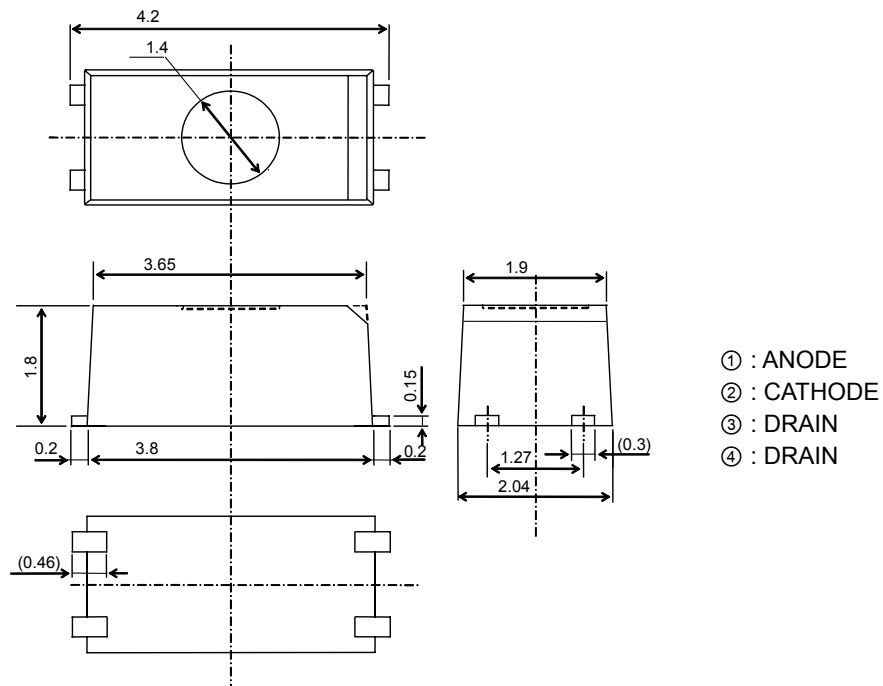
(Note 3) : SWITCHING TIME TEST CIRCUIT







OUTLINE DRAWING



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